## Highly Sensitive, Selective and Stable NO<sub>2</sub> Gas Sensors with PPb-Level Detection Limit on 2D-Platinum Diselenide Films <sup>+</sup>

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Figure S1 XPS result of 300 °C, 450 °C and 600 °C. Pt 4f spectra for (a) 300 °C (b) 450 °C and (c) 600 °C. and Se 3d spectra (d) 300 °C (e) 450 °C and (f) 600 °C.



Figure S2. Schematic setup of gas sensing measurement system.



Figure S3. The gas sensing response of PtSe<sub>2</sub> fabricated at 450 °C with and without UV illumination.



Figure S4 Real time NO<sub>2</sub> response of PtSe<sub>2</sub> fabricated at 450 °C and the NO<sub>2</sub> concentration ranged from 50 ppb to 1 ppm at (a) 5 L, (b) 7 L, and (c) 10 L.

## Calculation of noise level (RMS) and limit of detection (LOD)

- Execute the linear fitting for plot of response versus NO<sub>2</sub> concentration and then extract the slope (sensitivity) and standard error in the linear region shown in figure S4(a) to (c)
- 2. Take 11 data points at the baseline before NO<sub>2</sub> response and execute the polynomial fit (5<sup>th</sup> order) shown in figure S4(d) to (f).
- 3. Take the regular residual of  $(Y_i-Y_{fit})$  of polynomial fit and calculate the root-mean squared deviation (RMS) and the LOD with the equation S1 and S2.

RMS (ppm<sup>-1</sup>) = 
$$\sqrt{V_i^2/(N-1)}$$
, where  $V_i = \sum (Y_i - Y_{fit})$ 



Limit of detection (ppm) = 3RMS/slope(sensitivity).

Figure S5 (a) to (c) the linear fit of the plot of the response versus concentration with 5, 7 and 10 layers. (d) to (f) 5<sup>th</sup> order polynomial fit of 11 points before gas purging in with 5, 7 and 10 layers.



Figure S6 (a) Real time  $NO_2$  response of  $PtSe_2$  fabricated at 450 °C with 7 layers and the  $NO_2$  concentration ranged from 1 ppm to 50 ppb. (b) and (c) the cycling response of 1 ppm and 50 ppb with 5 cycles.



Figure S7.  $PtSe_2$  sensing performance with (a) CO in 1 ppm (b)  $H_2S$  in 0.5 ppm, and (c)  $NH_3$  in 1 ppm



Figure S8. The cross section TEM image of PtSe<sub>2</sub> fabricated at 300 °C, 450 °C and 600 °C in low and high magnification. (a) and (d) are 300 °C, (b) and (e) are 450 °C, (d) and (f) are 600 °C.

## Band gap calculation through absorption spectrum and Tauc plot.

- 1. We can directly measure the absorption spectrum by fabricating PtSe<sub>2</sub> on quartz substrate.
- 2. Calculation the absorptance ( $\alpha$ ) through -log (absorption (%))/thickness
- 3. According to the formula:  $(\alpha hv)^{1/n} = A(hv E_g)$ , where the value n is 2 for indirect band, we can extrapolate the linear region of abscissa.



Figure S9. The absorption spectrum of PtSe<sub>2</sub> with different growth temperature in (a) 5 L, (b) 7 L, and (c) 10 L. The Tauc plot of abscissa of PtSe<sub>2</sub> with different temperature in (d) 5 L, (e) 7L and (f) 10 L.